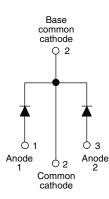


VS-HFA12PA120CPbF, VS-HFA12PA120C-N3

Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 2 x 6 A





PRODUCT SUMMARY								
Package	TO-247AC							
I _{F(AV)}	2 x 6 A							
V _R	1200 V							
V _F at I _F	2.4 V							
t _{rr} typ.	26 ns							
T _J max.	150 °C							
Diode variation	Single die							

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC®-JESD47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA12PA120C... is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. The VS-HFA12PA120C... has basic ratings of 1200 V and 6 A per leg continuous current. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{BBM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA12PA120C... is ideally suited for applications in power supplies and power conversion systems (such as inverters, converters, UPS systems, and power factor correction circuits), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Cathode to anode voltage	V _R		1200	V				
Maximum continuous forward currentper leg		T _C = 100 °C	6					
per device	IF	$1_{\rm C} = 100$ C	12	А				
Single pulse forward current	I _{FSM}		80	A				
Maximum repetitive forward current	I _{FRM}		24					
Maximum neuror dissinction	Р	T _C = 25 °C	62.5	W				
Maximum power dissipation	P _D	T _C = 100 °C	25	vv				
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C				

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RoHS

COMPLIANT

HALOGEN

FREE



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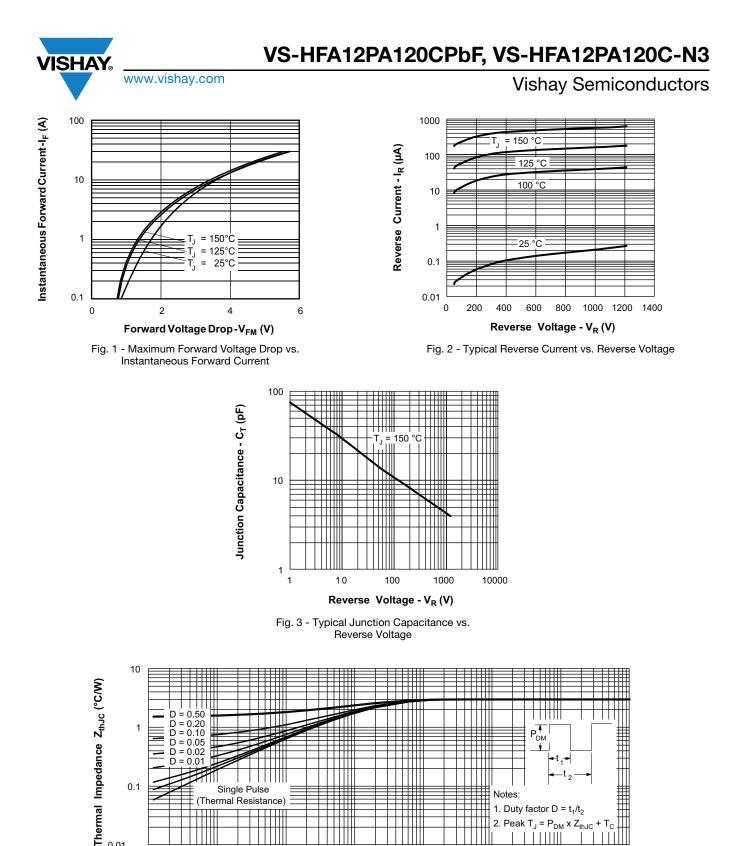
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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-					
Maximum forward voltage		I _F = 6 A	-	2.7	3.0	V				
	V _{FM}	I _F = 12 A	-	3.5	3.9					
		I _F = 6 A, T _J = 125 °C	-	2.4	2.8					
Maximum reverse		$V_{R} = V_{R}$ rated	-	0.26	5.0					
leakage current	I _{RM}	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	-	110	500	μΑ				
Junction capacitance	CT	V _R = 200 V	-	9.0	14	pF				
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	A/ μ s, V _R = 30 V	-	26	-	ns	
Reverse recovery time	t _{rr1}	T _J = 25 °C		-	53	80		
	t _{rr2}	T _J = 125 °C	I _F = 6 A dI _F /dt = 200 A/μs V _R = 200 V	-	87	130		
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	4.4	8.0	- A nC - Α/μs	
	I _{RRM2}	T _J = 125 °C		-	5.0	9.0		
	Q _{rr1}	T _J = 25 °C		-	116	320		
Reverse recovery charge	Q _{rr2}	T _J = 125 °C		-	233	585		
Peak rate of fall of recovery current during t _b	dl _{(rec)M} /dt1	T _J = 25 °C		-	180	-		
	dl _{(rec)M} /dt2	T _J = 125 °C		-	100	-		

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS					
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C				
Thermal resistance, junction to case	R _{thJC}		-	-	2.0					
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	K/W				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.50	-					
Weight			-	2.0	-	g				
weight			-	0.07	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style TO-247AC (JEDEC)	HFA12PA120C							

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t₁, Rectangular Pulse Duration (s) Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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1. Duty factor D = t_1/t_2 2. Peak T_I = P_{DM} x $Z_{th/C}$ + T_C

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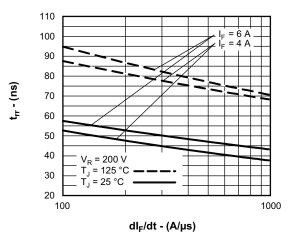
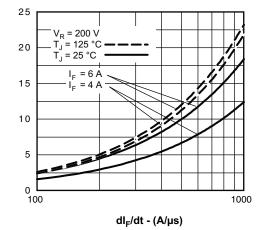
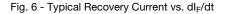


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt





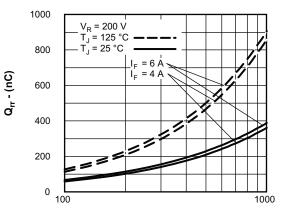




Fig. 7 - Typical Stored Charge vs. dl_F/dt

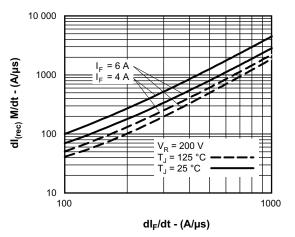


Fig. 8 - Typical dI_{(rec)M}/dt vs. dI_F/dt

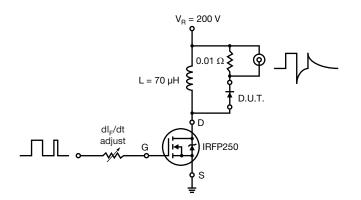


Fig. 9 - Reverse Recovery Parameter Test Circuit

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 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
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I_{rr} - (A)



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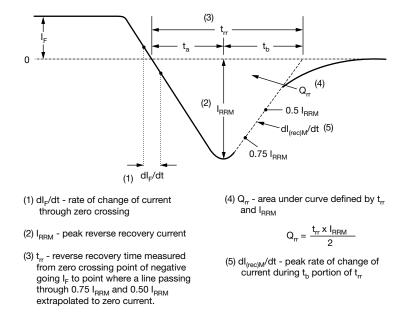


Fig. 10 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

1 2 3 4 5 6 7 8 1 - Vishay Semiconductors product 2 - HEXFRED® family 3 - Electron irradiated 4 - Current rating (12 = 12 A) 5 - PA = TO-247AC 6 - Voltage rating: (120 = 1200 V) 7 - Circuit configuration C = common cathode 8 8 -
 HEXFRED[®] family Electron irradiated Current rating (12 = 12 A) PA = TO-247AC Voltage rating: (120 = 1200 V) Circuit configuration C = common cathode

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-HFA12PA120CPbF	25	500	Antistatic plastic tube							
VS-HFA12PA120C-N3	25	500	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95542					
Part marking information	TO-247ACPbF	www.vishay.com/doc?95226					
	TO-247AC-N3	www.vishay.com/doc?95007					

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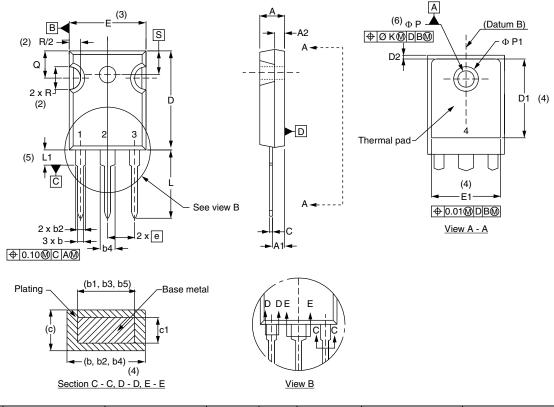
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TO-247AC - 50 mils L/F

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES SYMBO		MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			e	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØР	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51	BSC	0.217	BSC	
D1	13.08	-	0.515	-	4							

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension c and Q

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